## **2ch VOLTAGE DETECTOR**

±1.0%

#### ■ GENERAL DESCRIPTION

The NJU7710/11 is a 2ch low quiescent current voltage detector featuring high precision detection voltage.

The detection voltage is internally fixed with an accuracy of 1.0%.

NJU7710 is Nch. Open Drain and NJU7711 is a C-MOS output type.

#### ■ FEATURES

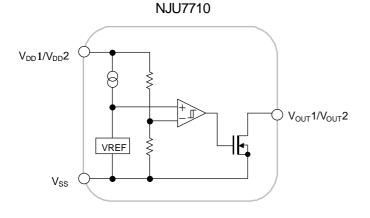
- High Precision detection Voltage
- Low Quiescent Current
- Detection Voltage Range
- Output Configuration
- Package Outline

#### ■ PIN CONFIGURATION

5 4 PIN FUNCTION 1. Vour1 2. Vss 3. Vpp1 1 2 3 4. Vpp2 5. Vour2

NJU7710F/F3, NJU7711F/F3

#### ■ EQUIVALENT CIRCUIT



#### 0.8µA typ. (per 1CH) 1.3~6.0V(0.1V step) NJU7710: Nch. Open Drain Type NJU7711: C-MOS Output Type SOT-23-5 / SC88A

New Japan Radio Co., Ltd.

NJU7711





NJU7710/11F NJ

NJU7710/11F3

NJU7710/11

## ■ DETECTION VOLTAGERANK LIST

NJU7710

Device Name	Package	V <sub>DET</sub>		
Device Name	Fackage	CH1	CH2	
NJU7710F1524*		1.5V	2.4V	
NJU7710F2318*	SOT-23-5	2.3V	1.8V	
NJU7710F0435		4.0V	3.5V	
NJU7710F4227		4.2V	2.7V	
NJU7710F0613*		6.0V	1.3V	
NJU7710F3-1524	SC88A	1.5V	2.4V	
NJU7710F3-2318		2.3V	1.8V	
NJU7710F3-0435		4.0V	3.5V	
NJU7710F3-4227		4.2V	2.7V	
NJU7710F3-0613		6.0V	1.3V	

\*Maintenance devices are not recommended for new designs

NJU7711

Device Name	Package	V <sub>DET</sub>		
Device Name	Fackage	CH1	CH2	
NJU7711F4219	SOT-23-5	4.2V	1.9V	
NJU7711F4227		4.2V	2.7V	
NJU7711F0613		6.0V	1.3V	
NJU7711F3-4219	SC88A	4.2V	1.9V	
NJU7711F3-4227		4.2V	2.7V	
NJU7711F3-0613		6.0V	1.3V	

#### ■ NJU7710

■ ABSOLUTE MAXIMUM	(Ta=25°C)				
PARAMETER	SYMBOL	RATINGS		UNIT	
Input Voltage	V <sub>DD</sub>	+10		V	
Output Voltage	V <sub>OUT</sub>	V <sub>SS</sub> -0.3 ~ +10		V	
Output Current	Ι <sub>Ουτ</sub>	50		mA	
Power Dissipation		SOT-23-5	350(*1)		
	PD		200(*2)	mW	
		SC88A	250(*1)		
Operating Temperature	Topr	-40 ~ +85		°C	
Storage Temperature	Tstg	-40 ~ +125		°C	

(\*1) : Mounted on glass epoxy board based on EIA/JEDEC. (114.3x76.2x1.6mm: 2Layers)

(\*2): Device itself

#### ■ ELECTRICAL CHARACTERISTICS

(CH1/2 common characteristics, Ta=25°C)

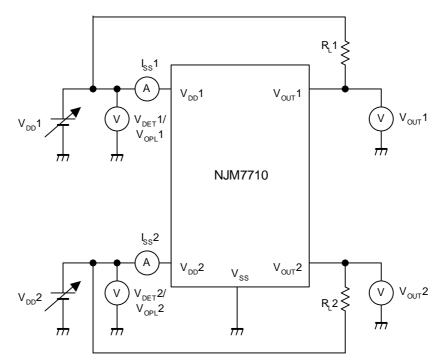
PARAMETER	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Detection Voltage	$V_{\text{DET}}$			-1.0%	_	+1.0%	V
Hysterisis Voltage	V <sub>HYS</sub>			V <sub>DET</sub> ×0.03	V <sub>DET</sub> ×0.05	V <sub>DET</sub> ×0.08	V
Quiescent Current	1	V <sub>DD</sub> =V <sub>DET</sub> +1V	V <sub>DET</sub> =1.3V~1.7V Version	_	0.5	1.0	μA
	I <sub>SS</sub>		V <sub>DET</sub> =1.8V~6.0V Version	-	0.8	1.6	μA
Output Current IouT		Nch,V <sub>DS</sub> =0.5V	V <sub>DD</sub> =1.2V	0.75	2.0	_	mA
	IOUT		V <sub>DD</sub> =2.4V (≥2.7V Version)	4.5	7.0	_	mA
Output Leak Current	I <sub>LEAK</sub>	V <sub>DD</sub> =V <sub>OUT</sub> =9V		_	_	0.1	μA
Detection Voltage Temperature Coefficient	ΔV <sub>DET</sub> /ΔTa	Ta=0 ~ +85°C		_	±100	_	ppm/°C
Operating Voltage (*3)	V <sub>DD</sub>	$R_L=100k\Omega$		0.8	_	9	V

(\*3): The minimum Operating Voltage(V\_{OPL}) indicates the same value of the input voltage(V\_{DD}) on

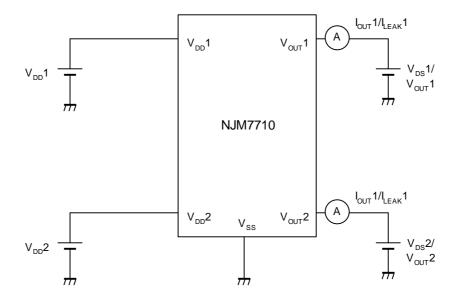
condition that  $V_{OUT}$  becomes 10% or less of the input voltage( $V_{DD}$ ).

### ■ TEST CIRCUIT

① COMMON TEST CIRCUIT

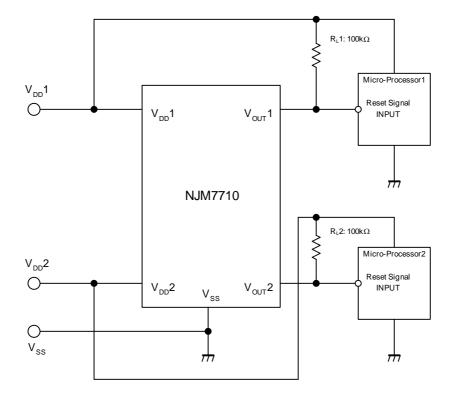


#### ② Output Current/Output Leak Current TEST CIRCUIT



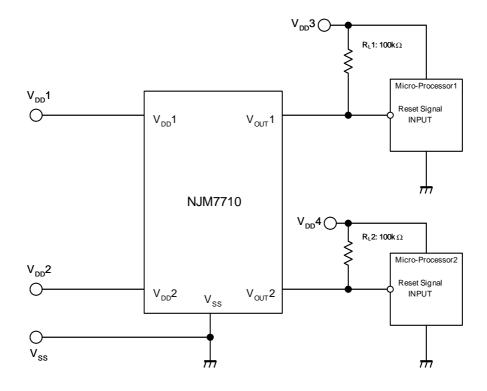
#### ■ TYPICAL APPLICATION

① Power supply voltage supervision of two systems



② Power supply voltage supervision of two systems

(At the time of power source supply classified by micro-processor)



# NJU7710/11

#### NJU7711

■ ABSOLUTE MAXIMUM	(Ta=25°C)			
PARAMETER	SYMBOL	RATINGS		UNIT
Input Voltage	V <sub>DD</sub>	+10		V
Output Voltage	Vout	$V_{SS}$ -0.3 ~ $V_{DD}$ +0.3		V
Output Current	Ι <sub>Ουτ</sub>	50		mA
Power Dissipation		PD SOT-23-5	350(*4)	
	PD		200(*5)	mW
		SC88A	250(*4)	
Operating Temperature	Topr	-40 ~ +85		°C
Storage Temperature	Tstg	-40 ~ +125		°C

(\*4) : Mounted on glass epoxy board based on EIA/JEDEC. (114.3x76.2x1.6mm: 2Layers)

(\*5) : Device itself

#### ■ ELECTRICAL CHARACTERISTICS

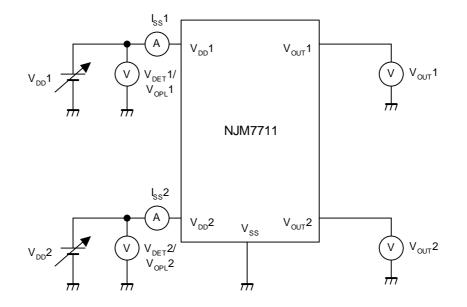
(CH1/2 common characteristics. Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION			TYP.	MAX.	UNIT
Detection Voltage	V <sub>DET</sub>			-1.0%	—	+1.0%	V
Hysterisis Voltage	V <sub>HYS</sub>			V <sub>DET</sub> x0.03	V <sub>DET</sub> x0.05	V <sub>DET</sub> x0.08	V
Quiescent Current I <sub>SS</sub>		VDET=1.3V~1.7V Version	_	0.5	1.0	μA	
	V <sub>DD</sub> =V <sub>DET</sub> +1V	VDET=1.8V~6V Version	-	0.8	1.6	μA	
		Nch, V <sub>DS</sub> =0.5V	V <sub>DD</sub> =1.2V	0.75	2.0	_	mA
Output Current I <sub>OUT</sub>			V <sub>DD</sub> =2.4V (≥2.7V Version)	4.5	7.0	_	mA
	I <sub>OUT</sub>	Pch, V <sub>DS</sub> =0.5V	V <sub>DD</sub> =4.8V (≤3.9V Version)	2.0	3.5	_	mA
			V <sub>DD</sub> =6.0V (4V~5.6V Version)	2.5	4.0	_	mA
		V <sub>DD</sub> =8.4V (≥5.7V Version)	3.0	5.0	_	mA	
Detection Voltage Temperature Coefficient	$\Delta V_{DET} / \Delta Ta$	Ta=0 ~ +85°C		_	±100	_	ppm/°C
Operating Voltage (*6)	V <sub>DD</sub>	R <sub>L</sub> =100kΩ		0.8	_	9	V

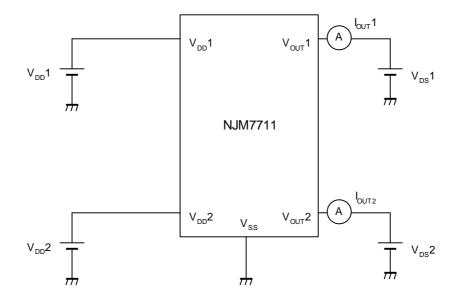
(\*6): The minimum Operating Voltage( $V_{OPL}$ ) indicates the same value of the output voltage( $V_{OUT}$ ) on condition that  $V_{OUT}$  becomes 10% or less of the input voltage( $V_{DD}$ ).

#### ■ TEST CIRCUIT

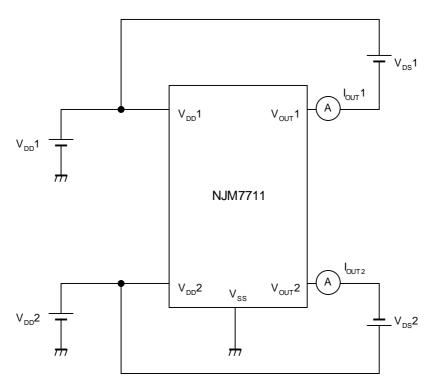
#### ① COMMON TEST CIRCUIT



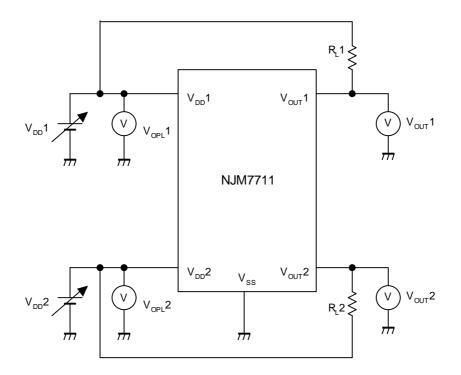
#### ② Nch Output Current TEST CIRCUIT



③ Pch Output Current TEST CIRCUIT

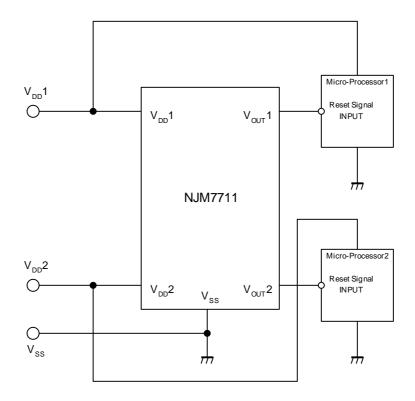


Minimum Operating Voltage TEST CIRCUIT



#### ■ TYPICAL APPLICATION

Power supply voltage supervision of two systems





#### [CAUTION]

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